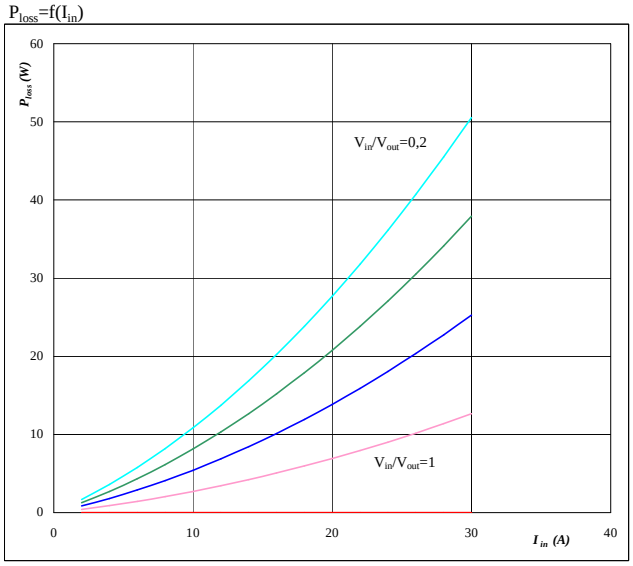
General conditions

BOOST		
V_{GEon}	=	15 V
V_{GEoff}	=	0 V
R_{gon}	=	4 Ω
R_{goff}	=	4 Ω

Figure 1. IGBT

Typical average static loss as a function of input current I_{RMS}

$P_{loss}=f(I_{in})$



Conditions: T_j= 150 °C

Ratio of input DC voltage to output DC voltage

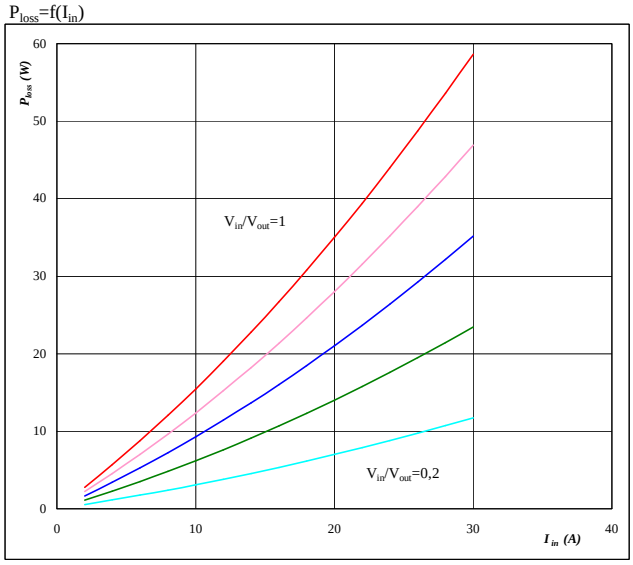
parameter: V_{in}/V_{out} from 0,2 to 1,0

in 0,2 steps

Figure 2. FWD

Typical average static loss as a function of input current I_{RMS}

$P_{loss}=f(I_{in})$



Conditions: T_j= 150 °C

Ratio of input DC voltage to output DC voltage

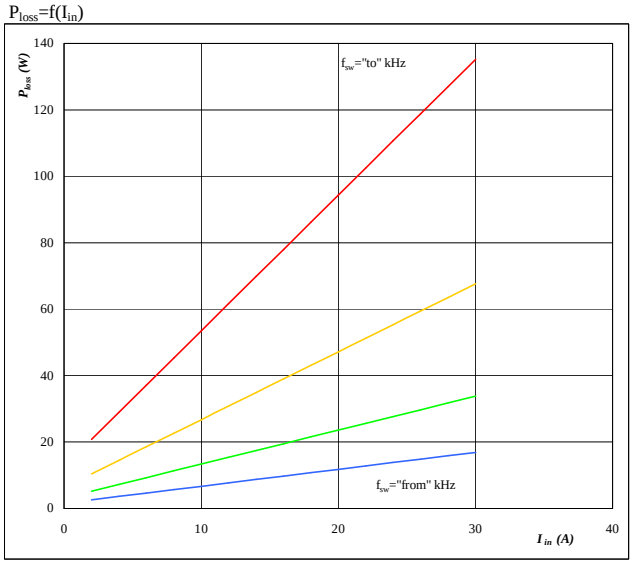
parameter: V_{in}/V_{out} from 0,2 to 1,0

in 0,2 steps

Figure 3. IGBT

Typical average switching loss as a function of input current

$P_{loss}=f(I_{in})$



Conditions: Tj= 150 °C

V_{out} = 700 V

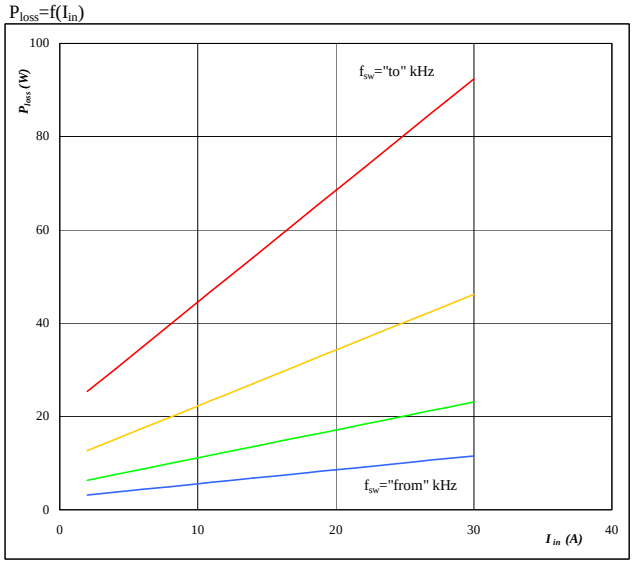
Sw. freq. fsw from 4 kHz to 32 kHz

in steps of factor 2

Figure 4. FWD

Typical average switching loss as a function of input current

$P_{loss}=f(I_{in})$



Conditions: Tj= 150 °C

V_{out} = 700 V

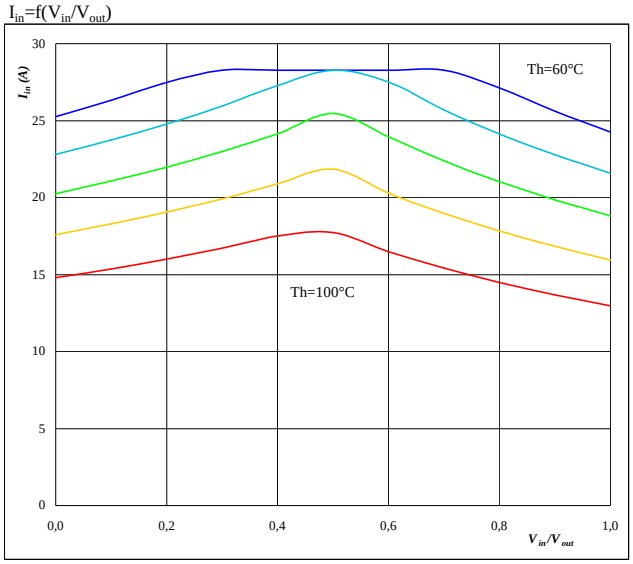
Sw. freq. fsw from 4 kHz to 32 kHz

in steps of factor 2

Figure 5. per PHASE

Typical available input current as a function of V_{in}/V_{out}

$I_{in}=f(V_{in}/V_{out})$

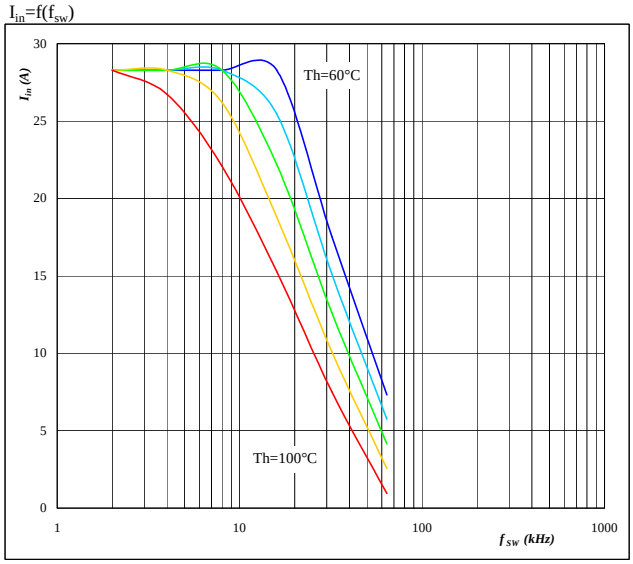


Conditions: T_j= T_{jmax}-25°C
DC link= 700 V f_{sw}= 16 kHz
parameter: Heatsink temp.
Th from 60 °C to 100 °C
in 10 °C steps

Figure 6. per PHASE

Typical available input current as a function of switching frequency

$I_{in}=f(f_{sw})$

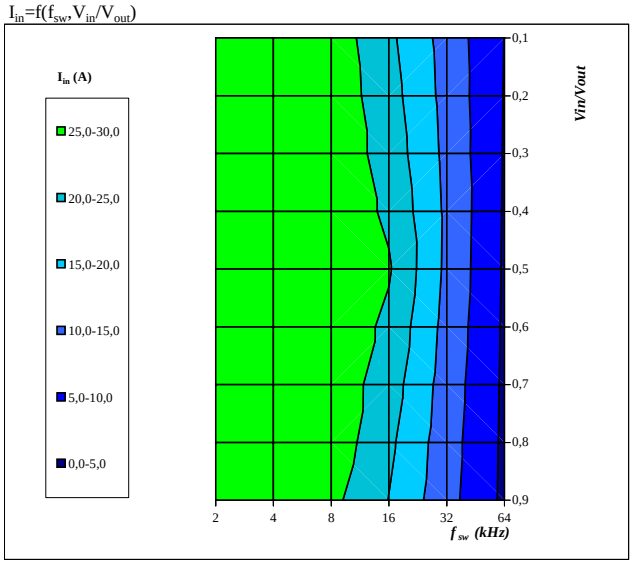


Conditions: T_j= T_{jmax}-25°C
DC link= 700 V Vin 500 V
parameter: Heatsink temp.
Th from 60 °C to 100 °C
in 10 °C steps

Figure 7. per PHASE

Typical available input current as a function of f_{sw} and V_{in}/V_{out}

$I_{in}=f(f_{sw},V_{in}/V_{out})$

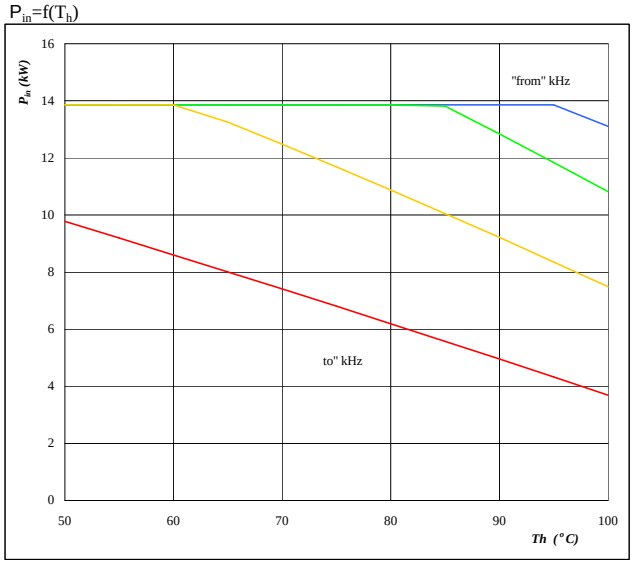


Conditions: Tj= T_{jmax}-25°C
DC link= 700 V
Th= 80 °C

Figure 8. per PHASE

Typical available electric input power as a function of heatsink temperature

$P_{in}=f(T_h)$

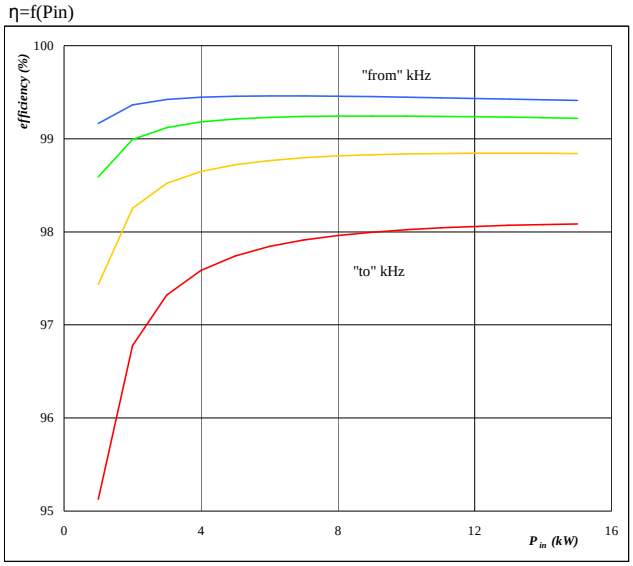


Conditions: Tj= T_{jmax}-25°C
Vin 500 V DC link= 700 V
Sw. freq. fsw from 4 kHz to 32 kHz

Figure 9. **per PHASE**

Typical efficiency as a function of input power

η=f(Pin)



Conditions:		Tj=	T_{jmax}-25°C		
	Vin	500	V	DC link=	700 V
parameter:					
Sw. freq.	fsw from	4	kHz to	32	kHz